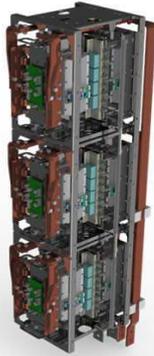


SKS C 120 GDD 69/11 – A3A MA B1C



SKiiP stack

Absolute maximum ratings ¹⁾

Symbol	Conditions	Values	Unit
$I_{IN\ MAX}$	Maximum permanent input current (4Q only)	1 200	A_{RMS}
$I_{OUT\ MAX}$	Maximum permanent output current	2 400	A_{RMS}
$V_{IN\ MAX}$	Maximum input voltage (4Q only)	760	V_{AC}
$V_{OUT\ MAX}$	Maximum output voltage	760	V_{AC}
$V_{BUS\ MAX}$	Maximum DC Bus voltage	1 200	V_{DC}
$F_{IN\ MAX}$	Inverter input frequency (4Q only)	100	Hz
$F_{OUT\ MAX}$	Inverter output frequency	100	Hz
$F_{SW\ MAX}$	Maximum switching frequency	5	kHz

Electrical characteristics: application example

$T_{AMBIENT}=40^{\circ}C$ unless otherwise specified

Symbol	Conditions	min	typ	max	Unit
AC phase Grid					
$I_{OUT\ RATED}$	Rated output current (4Q)		1 200		A_{RMS}
$I_{OUT\ RATED}$	Rated output current (2Q)		2 400		A_{RMS}
$I_{OUT\ OVL}$	Overload output current (4Q)		1 320		A_{RMS}
$I_{OUT\ OVL}$	Overload output current (2Q)		2 640		A_{RMS}
t_{OVL}	Overload duration		60		s
T_{OVL}	Time between 2 overloads		10		min
V_{OUT}	Output voltage	620	690	760	V_{AC}
P_{OUT}	Rated output power (4Q)		1 430		kW
P_{OUT}	Rated output power (2Q)		2 870		kW
F_{SW}	Inverter switching frequency		2		kHz
F_{OUT}	Output frequency		50		Hz
PF	Power factor		1		-
$P_{LOSS\ INV}^{2)}$	Losses at rated current		14 160		W
$\eta^{2)}$	Efficiency at rated current		99		%

AC phase Generator (4Q only)

$I_{IN\ RATED}$	Rated input current		1 200		A_{RMS}
$I_{IN\ OVL}$	Overload input current		1 320		A_{RMS}
t_{OVL}	Overload duration		60		s
T_{OVL}	Time between 2 overloads		10		min
V_{OUT}	Output voltage	620	690	760	V_{AC}
P_{OUT}	Rated output power		1 430		kW
F_{SW}	Inverter switching frequency		2		kHz
F_{OUT}	Output frequency		20	100	Hz
PF	Power factor		-1		-
$P_{LOSS\ INV}^{2)}$	Losses at rated current		14 160		W
$\eta^{2)}$	Efficiency at rated current		99		%

DC Bus

V_{BUS}	Rated DC voltage applied to the capacitor bank		1 100		V_{DC}
$V_{BUS\ MAX}$	Max DC voltage applied to the caps bank (max 30% of LTE)		1 200		V_{DC}
$\tau_{d5\%}$	Discharge time of the capacitors ($V_{DC} < 60\ V$)		6		min
C_{DC}	Capacitor bank capacity		14,0		mF
LTE	Calculated LTE of the capacitors with forced air cooling		100		kh

Stack Insulation

Crd	Minimum creepage distance		8,7		mm
Cld	Minimum clearance distance		7,1		mm
Visol	Chassis / Power stage AC/DC (insulation test voltage DC, 5 s)	-4 200		4 200	V_{DC}
Visol12	SKiiP driver only, output 1 / output 2 (AC, rms, 2 s)			1 500	V
dv/dt	SKiiP driver only, secondary to primary side			75	kV/ μ s

SKiiPRACK® - Type 3A

3-phase IGBT converter

This stack can be used as a 2Q 3-phase inverter or a 4Q converter. All values are valid for 2Q and 4Q configurations unless otherwise specified.

Ordering No. 08769360

Description 4Q / SKS C 120 GDD 69/11 – A3A MA B1C
2Q / SKS C 240 GD 69/11 – A3A MA B1C

Features

- Designed in regard to EN50178 recommendations
- Designed for a 600 x 600 x 2000 mm cabinet
- Embedded SKiiP® Technology 3
- SKiiP 2403GB172-4DW, Trench 3 1700V IGBT, CAL3 diode
- Integrated current and temperature sensors
- Water cooling

Typical Applications

- Wind generators (SG and DFIG)
- High power AC drives

Footnotes

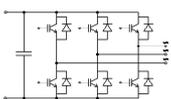
¹⁾ Absolute maximum ratings are values not to be exceeded in any case and do not imply that the stack can operate in all these conditions taken together

²⁾ fan consumption and losses in air included

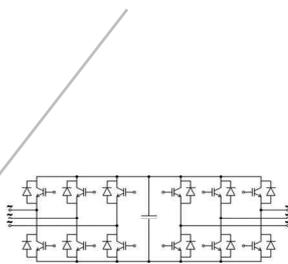
REMARKS

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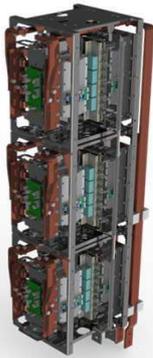
Before using the converter, please read carefully the SKiiPRACK® user manual.



B6CI



B6CI + B6CI



SKiiP stack

SKiiPRACK® - Type 3A

3-phase IGBT converter

This stack can be used as a 2Q 3-phase inverter or a 4Q converter. All values are valid for 2Q and 4Q configurations unless otherwise specified.

Ordering No. 08769360

Description 4Q / SKS C 120 GDD 69/11 – A3A MA B1C
2Q / SKS C 240 GD 69/11 – A3A MA B1C

Features

- Designed in regard to EN50178 recommendations
- Designed for a 600 x 600 x 2000 mm cabinet
- Embedded SKiiP® Technology 3
- SKiiP 2403GB172-4DW, Trench 3 1700V IGBT, CAL3 diode
- Integrated current and temperature sensors
- Water cooling

Typical Applications

- Wind generators (SG and DFIG)
- High power AC drives

Footnotes

¹⁾ the user shall ensure that the ambient air is sufficiently ventilated to avoid hot spots.

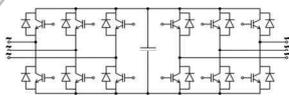
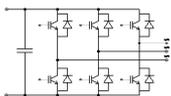
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Before using the converter, please read carefully the SKiiPRACK® user manual.

Environmental conditions		T _{AMBIENT} =40°C unless otherwise specified			
Characteristics	Conditions	min	typ	max	Unit
Climatic					
Ambient temperature ¹⁾	IEC 60721-3, class 1K2&2K2 Storage & transportation	-25		60	°C
	IEC 60721-3-3, class 3K3 extended In operation	-20		55	°C
Humidity	IEC 60721-3-3, class 3K3 no condensation no icing	5		85	%
Mechanical					
Installation altitude	without derating			1 000	m
Max. installation altitude	with derating			4 000	m
Protection degree	IEC 60529		IP00		-
Vibrations & Shocks	IEC 60721-3-2, Storage & transportation, 1 cell		2M1		-
	IEC 60721-3-3, in operation, 1 cell		3M3		-
Pollution degree	EN 50178		2		-
Mass	Cell		80		kg
	Full converter		275		kg
Thermal					
ΔV/Δt _{WATER}	Water flow per cell	8	12	24	L/min
	Water flow per converter	24	36	72	L/min
ΔP _{WATER}	Pressure drop per cell, 50% glycol, 12 L/min		130		mbar
	Pressure drop per converter, 50% glycol, 36 L/min		130		mbar
Water pressure	Maximum water pressure permissible per cell		3		bar
Coolant type	Recommended coolant		50% Glycol / 50% water		-
T _{INLET}	Cooling water inlet temperature	-20	45	60	°C
Required cooling airflow	Snubbers, airflow direction bottom-top		1		ms ⁻¹
V _{SUPPLY} [fan]	Capacitor DC fan operating voltage	18	24	28	V _{DC}
P _{FAN} per fan	Fan power consumption at typical voltage supply		3,6		W
LTE [fan]	Capacitor DC fan life time expectancy (L10 method)		65		kh

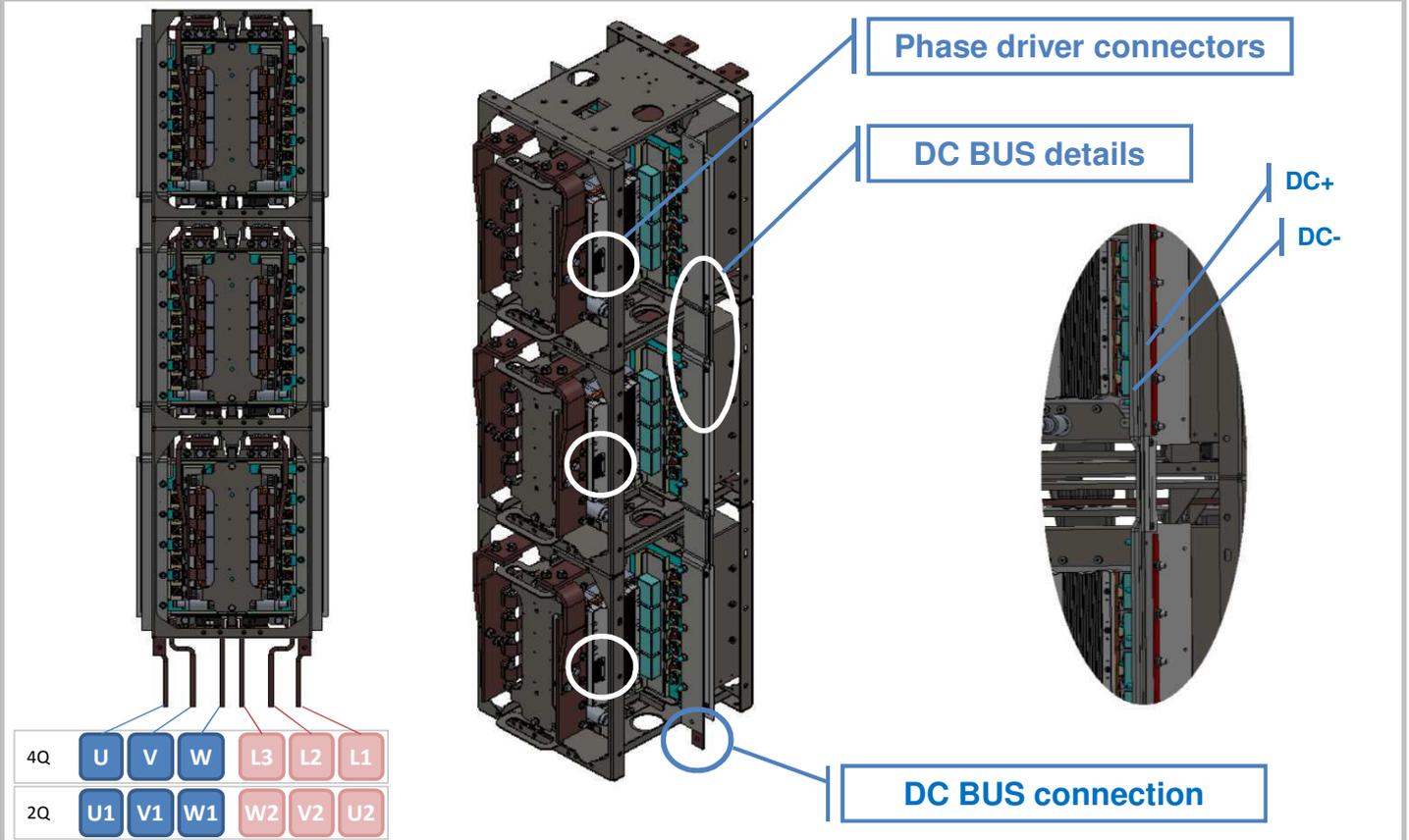
Gate Driver Characteristics		T _{AMBIENT} =25°C unless otherwise specified			
Symbol	Conditions	min	typ	max	Unit
Gate Driver / controller data					
V _{S2}	supply voltage non stabilized	13	24	30	V _{DC}
I _{S2}	VS2 = 13V - 30 V , F _{SW} in kHz, I _{AC} in A	330 + 55×F _{SW} + 0.00035×I _{AC} ²			mA
ViT+	input threshold voltage HIGH	12.3			V _{DC}
ViT-	input threshold voltage LOW			4.6	V _{DC}
R _{IN}	Input resistance		10		kΩ
C _{IN}	Input capacitance		1		nF
Measurement & protection					
HB_I	Analogue current signal analog OUT	245	250	255	A·V ⁻¹
I _{TRIPSC}	over current trip level (I _{analog OUT} =10V)	2 450	2 500	2 550	A _{PEAK}
CMN_TMP	Analogue temperature signal Th < 80°C	min	17 + 10,3×CMN_TMP		°C
		typ	19 + 10,5×CMN_TMP		°C
		max	20 + 10,5×CMN_TMP		°C
CMN_TMP	Analogue temperature signal Th > 80°C	min	26 + 8,8×CMN_TMP		°C
		typ	28 + 8,8×CMN_TMP		°C
		max	30 + 8,9×CMN_TMP		°C
T _{trip}	Over temperature protection	110	115	120	°C



B6CI

B6CI + B6CI

Electrical connection

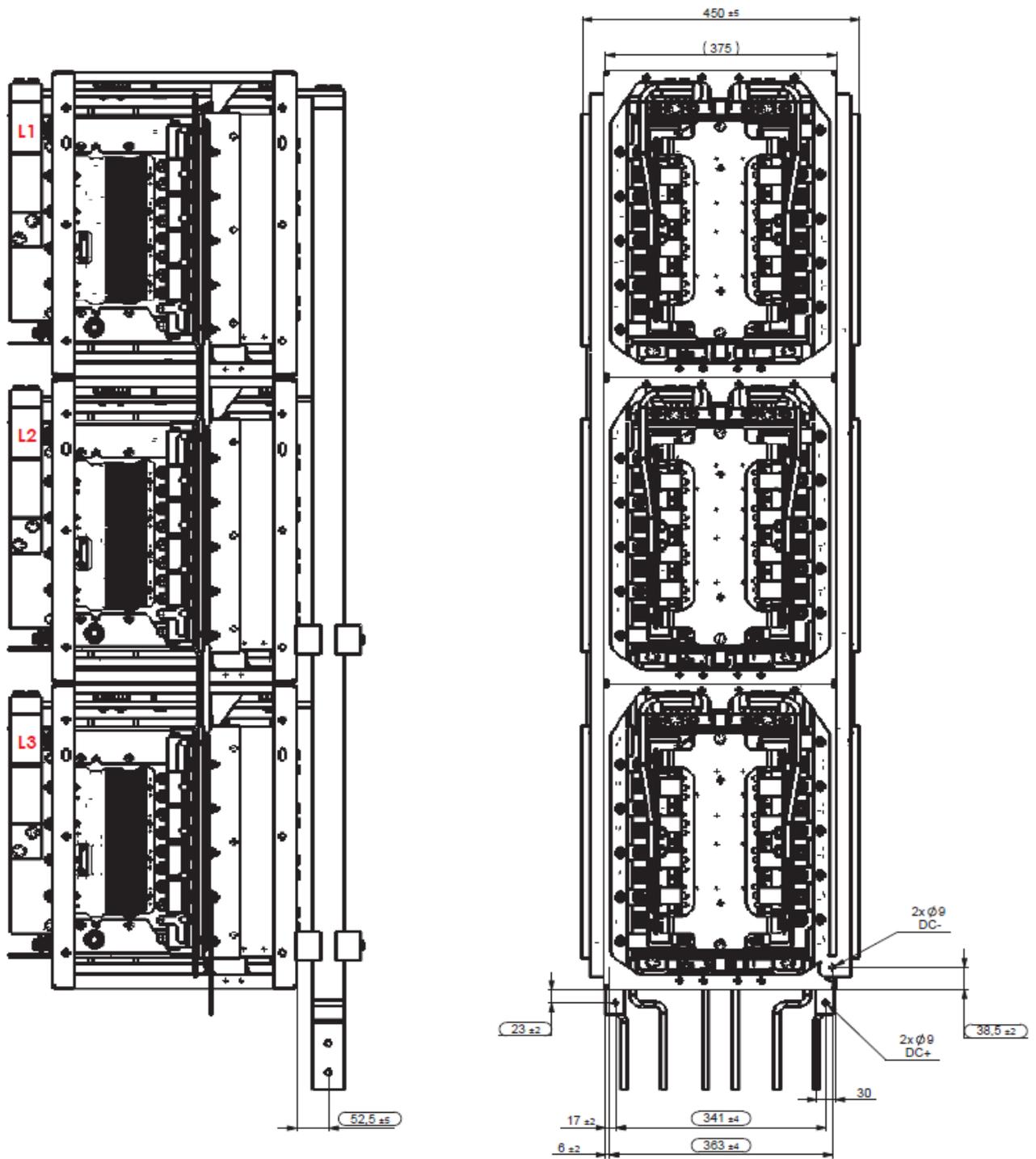


Phase Driver connector assignment

HE10-14 male connector

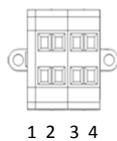
X1•		
Pin	Signal	Remark
1	Shield	
2	BOT IN (2)	positive 15V CMOS logic; 10 kΩ impedance, don't connect when using fiber optic
3	ERROR OUT (1)	LOW = NO ERROR; open Collector Output; max. 30 V / 15 mA don't connect when using fiber optic, propagation delay 1 μs min. pulsewidth error-memory-reset 9 μs
4	TOP IN (2)	positive 15V CMOS logic; 10 kΩ impedance don't connect when using fiber optic
5	Overtemp. OUT (1)	LOW = NO ERROR = ̸DCB < 115 + 5°C open collector Output; max. 30 V / 15 mA „low“ output voltage < 0,6 V „high“ output voltage max. 30 V
6	+ 24 VDC IN	24 V _{DC} supply
7	+ 24 VDC IN	24 V _{DC} supply supply voltage monitoring threshold 19,5 V
8	+15 VDC OUT	max. 50 mA auxiliary power supply
9	+15 VDC OUT	
10	GND	GND for power supply and
11	GND	GND for digital signals
12	Temp. analog OUT	max output current 5mA
13	GND aux	reference for analog output signals
14	I analog OUT	SKiiP 3 with Al2O3 ceramic substrate current actual value 8,0 V ⇔ 100 % IC @ 25 °C overcurrent trip level 10 V ⇔ 125 % IC @ 25 °C current value > 0 ⇔ SKiiP system is source current value < 0 ⇔ SKiiP system is sink SKiiP 3 with AlN ceramic substrate: refer to corresponding datasheet

1) Open collector output, external pull up resistor necessary
added signal to GND



RIGHT SIDE VIEW

FRONT VIEW



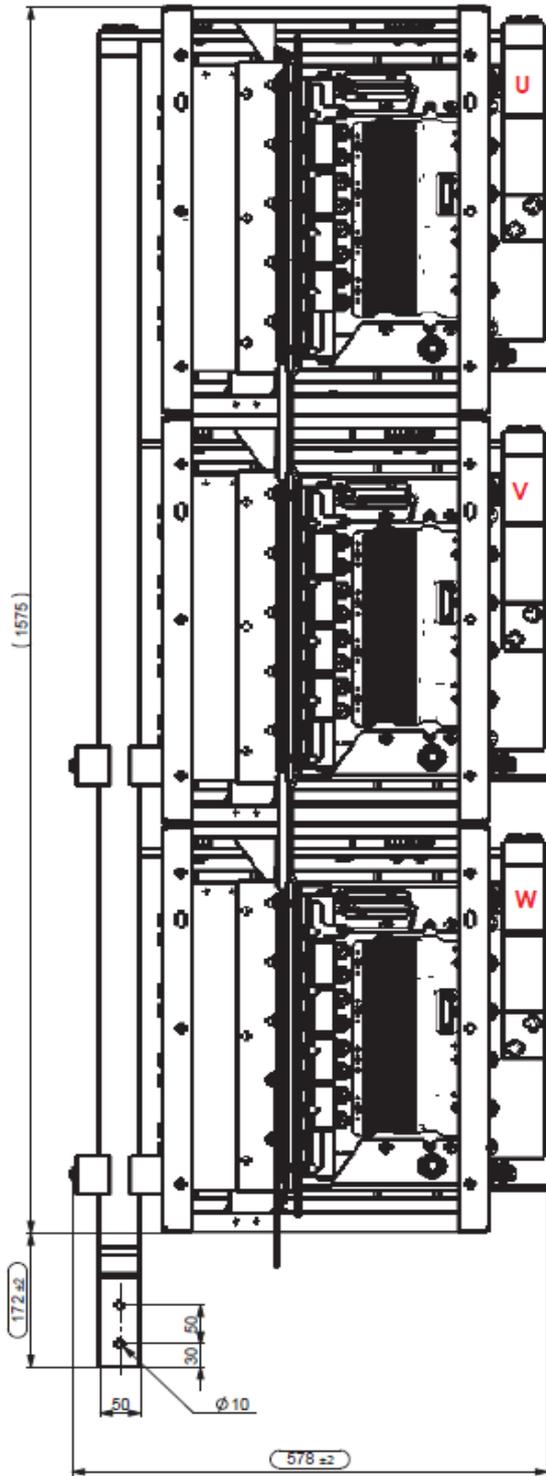
1 2 3 4

Pin	Designation
1	+24VDC
2	+24VDC
3	GND
4	GND

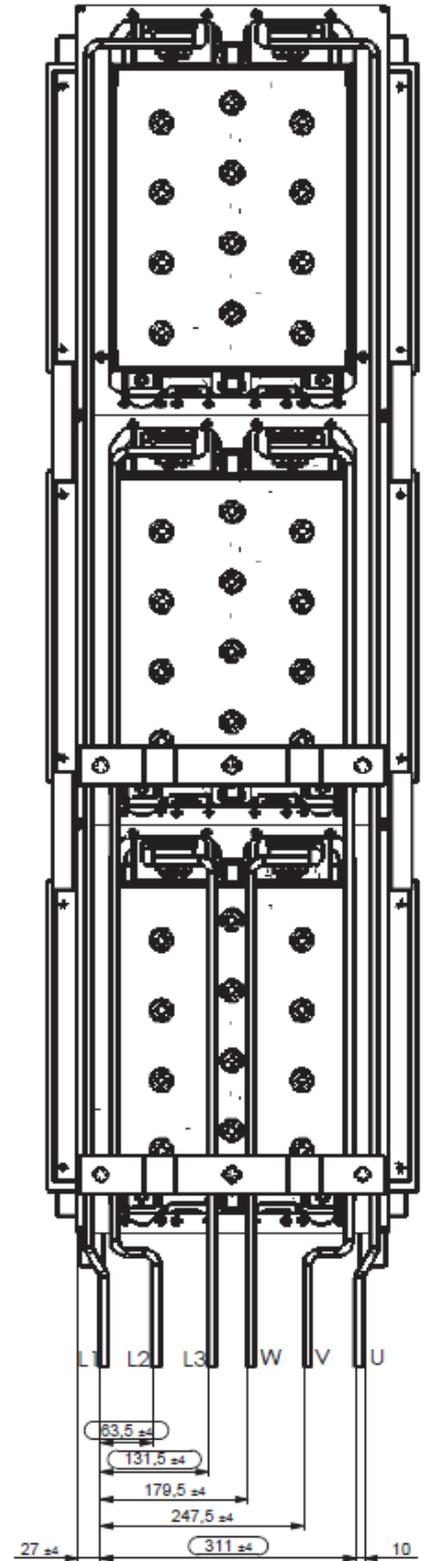
DC FAN CONNECTION (6 times)

Dimensions

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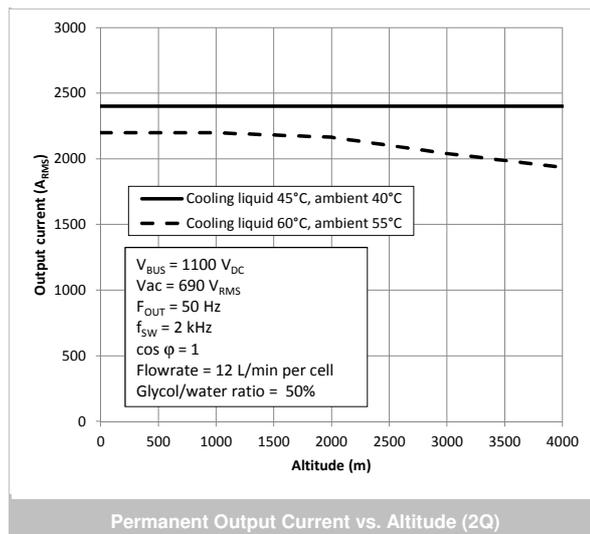
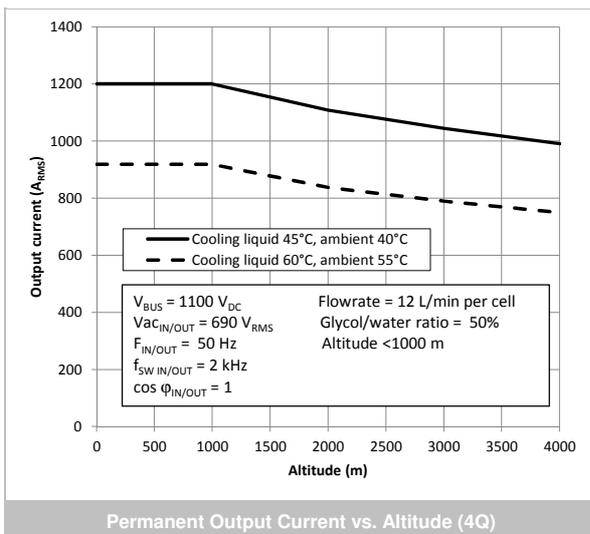
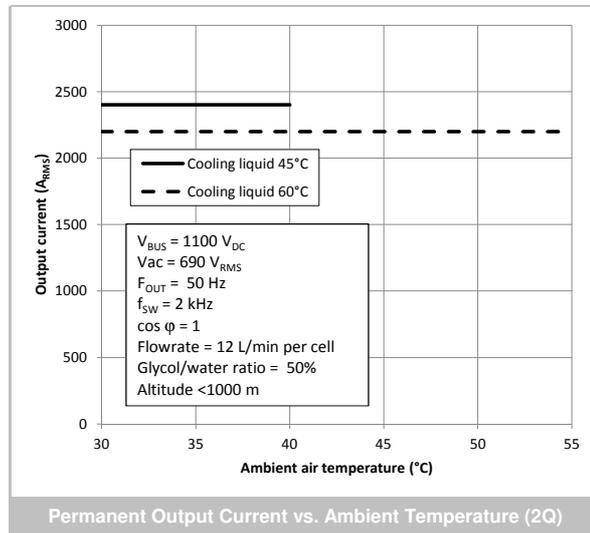
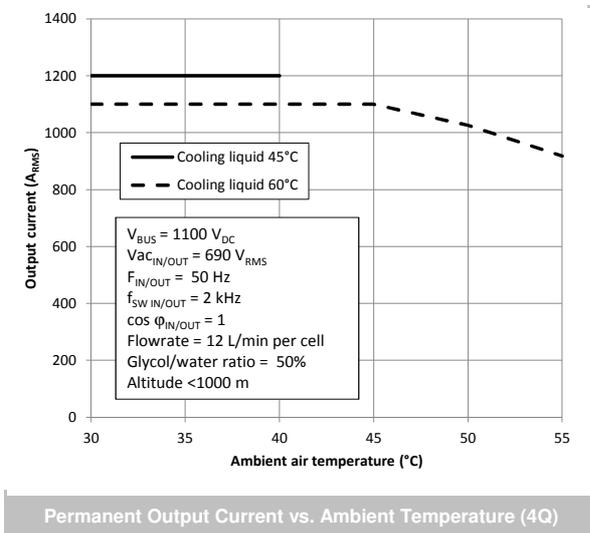
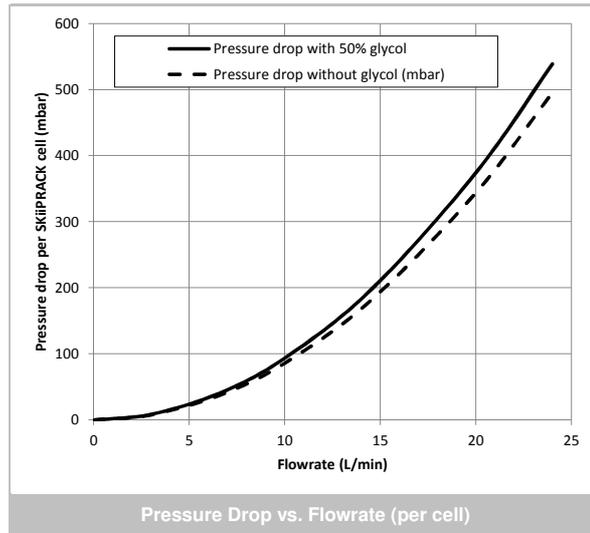
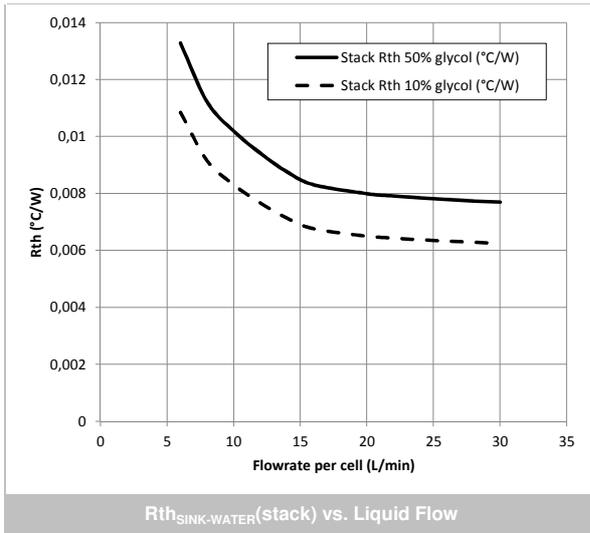
LEFT SIDE VIEW

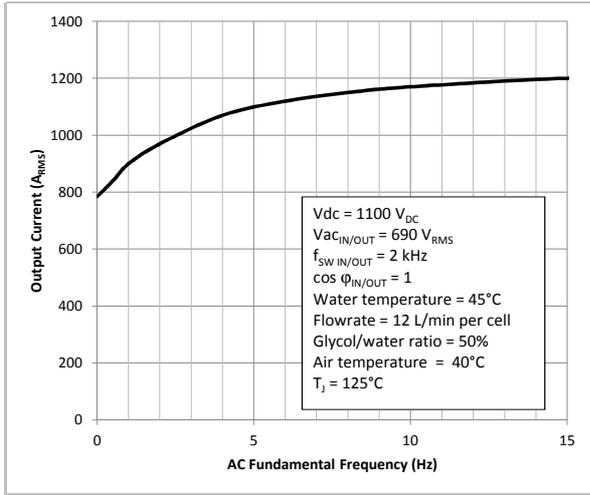


REAR VIEW

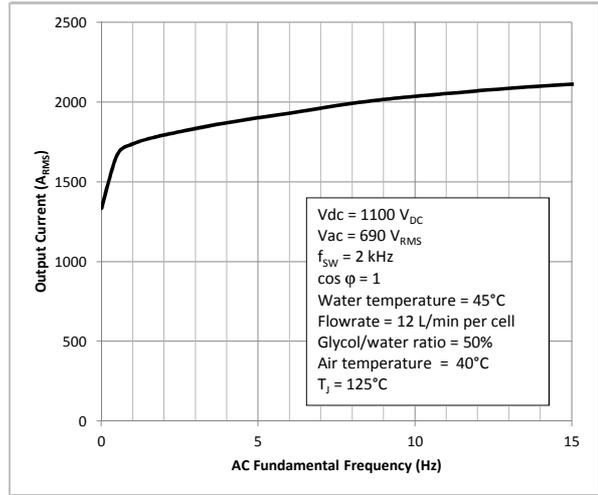
Dimensions

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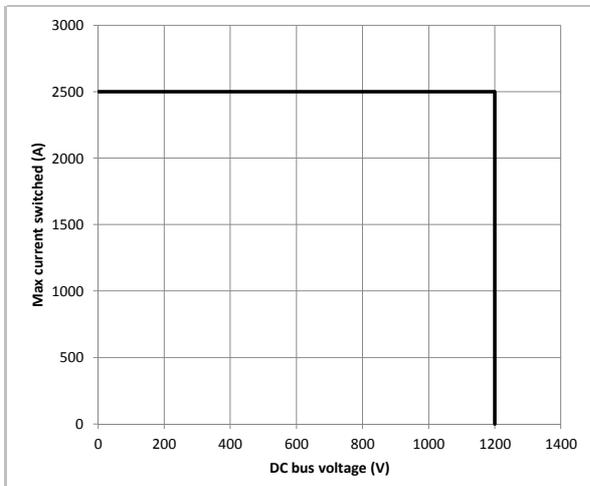




Permanent Output Current vs. Output Frequency (4Q)



Permanent Output Current vs. Output Frequency (2Q)



Safe Operating Area (per SKiP)